2SC1345

Silicon NPN Epitaxial

REJ03G0687-0300
(Previous ADE-208-1052A)
Rev.3.00
Sep.10.2005

Application

Low frequency low noise amplifier

Outline

RENESAS Package code: PRSS0003DA-A
(Package name: TO-92 (1))

1. Emitter
2. Collector
3. Base

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	55	V
Collector to emitter voltage	V_{CEO}	50	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Collector power dissipation	P_C	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	55	—	—	V	I_C = –10 µA, I_E = 0
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	50	—	—	V	I_C = 1 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	I_E = 10 µA, I_C = 0
Collector cutoff current	I_{CBO}	—	—	0.5	µA	V_{CB} =18 V, I_E = 0
Emitter cutoff current	I_{EBO}	—	—	0.5	µA	V_{EB} = 2 V, I_C = 0
DC current transfer ratio	h_{FE}*[1]	250	—	1200		V_{CE} = 12 V, I_C = 2 mA
Base to emitter voltage	V_{BE}	—	—	0.75	V	V_{CE} = 12 V, I_C = 2 mA
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	0.5	V	I_C = 10 mA, I_B = 1 mA
Gain bandwidth product	f_T	—	230	—	MHz	V_{CE} = 12 V, I_C = 2 mA
Collector output capacitance	Cob	—	—	3.5	pF	V_{CB} = 10 V, I_E = 0, f = 1 MHz
Noise figure	NF	—	—	8	dB	V_{CE} = 6 V, I_C = 0.1 mA, f = 10 Hz, R_g = 10 kΩ
		—	—	1	dB	V_{CE} = 6 V, I_C = 0.1 mA, f = 1 kHz, R_g = 10 kΩ

Note: 1. The 2SC1345 is grouped by h_{FE} as follows.

D	E	F
250 to 500	400 to 800	600 to 1200

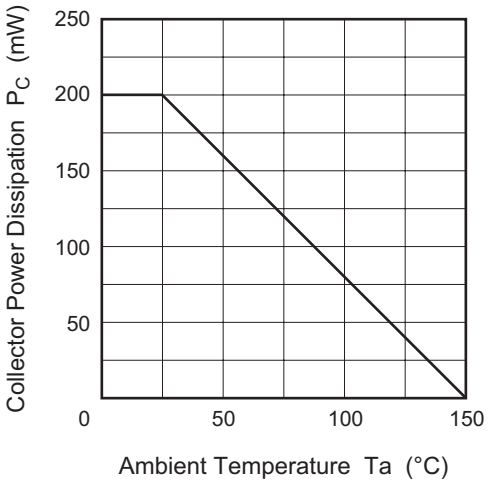
Small Signal h Parameters

(V_{CE} = 5V, I_C = 0.1 mA, f = 270 Hz, Ta = 25°C, Emitter common)

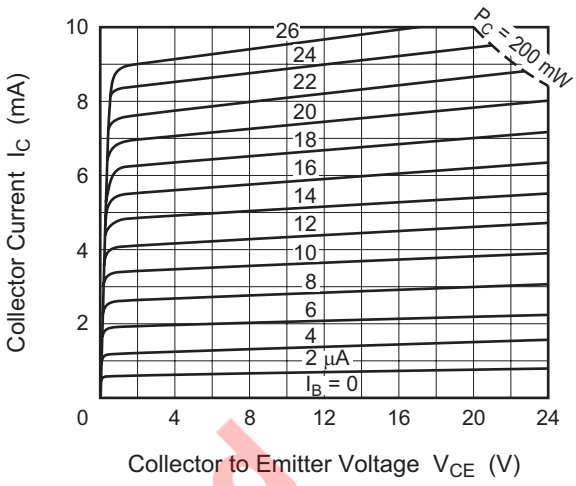
Item	Symbol	D	E	F	Unit
Input impedance	hie	110	170	240	kΩ
Voltage feedback ratio	hre	9.5	14.5	16	$\times 10^{-4}$
Current transfer ratio	hfe	340	540	825	
Output admittance	hoe	12.0	12.5	13.5	µS

Main Characteristics

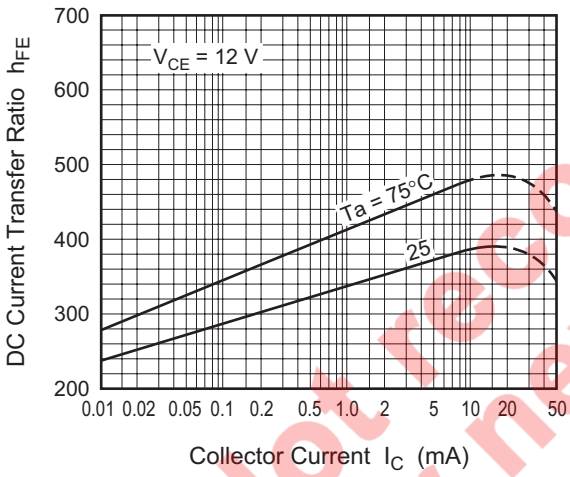
Maximum Collector Dissipation Curve



Typical Output Characteristics



DC Current Transfer Ratio vs. Collector Current



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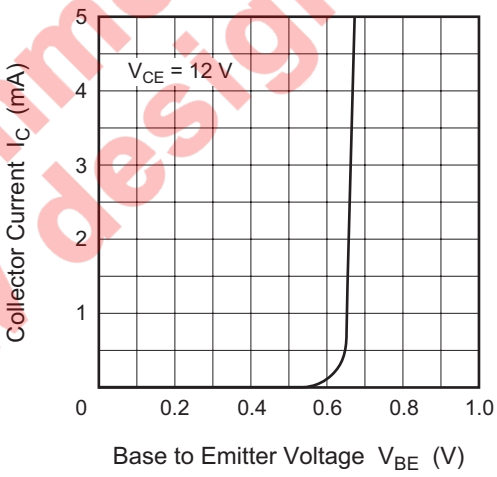
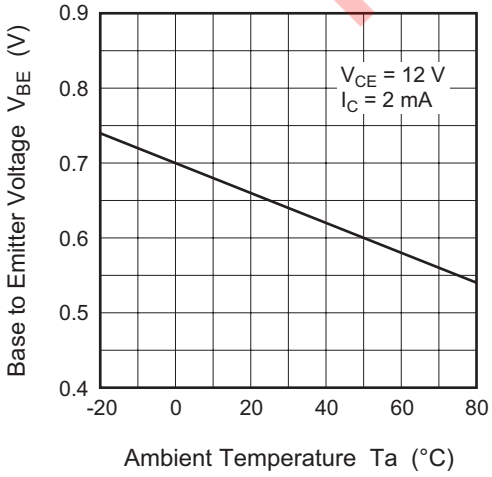
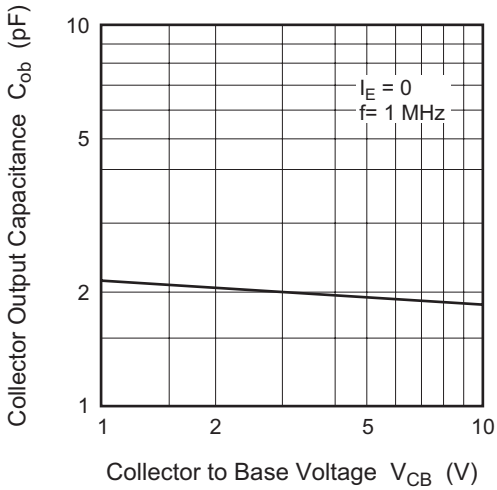


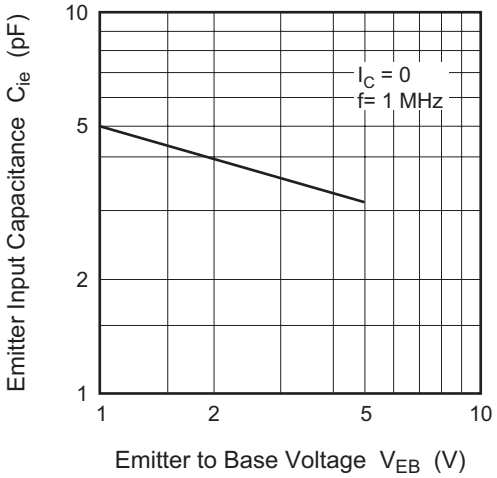
Base to Emitter Voltage vs. Ambient Temperature



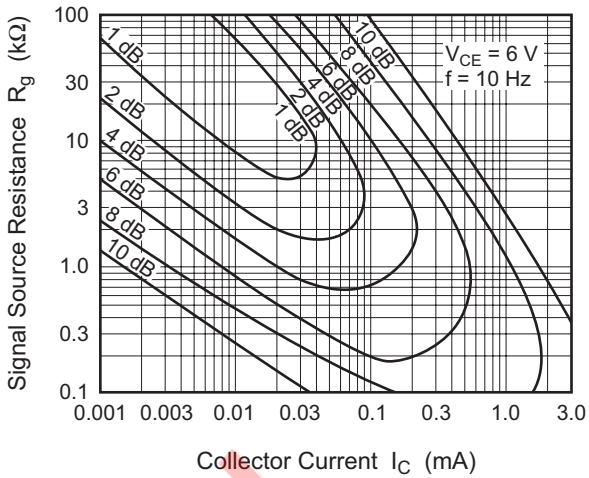
Collector Output Capacitance vs. Collector to Base Voltage



Emitter Input Capacitance vs. Emitter to Base Voltage



Contours of Constant Noise Figure



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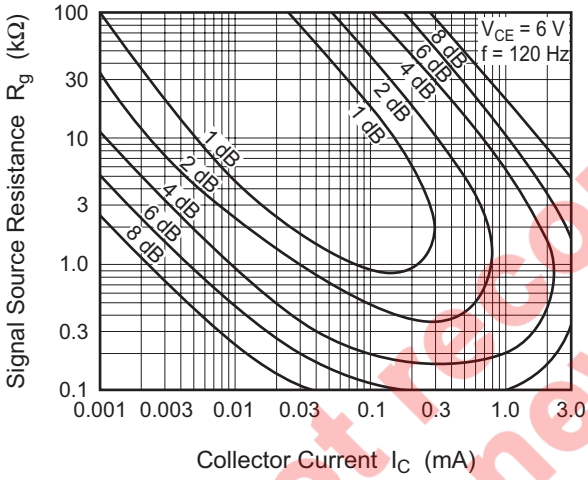

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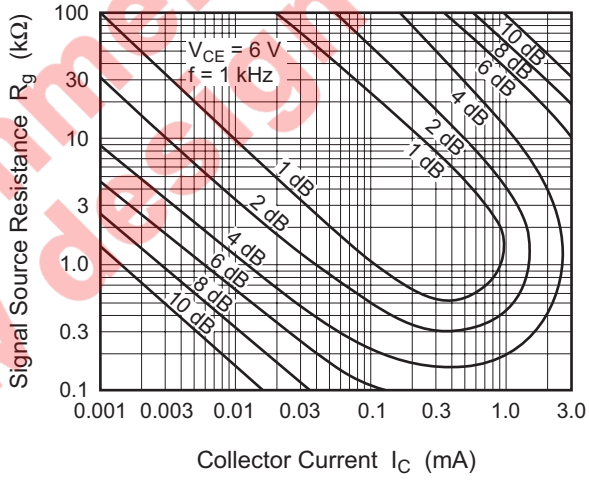
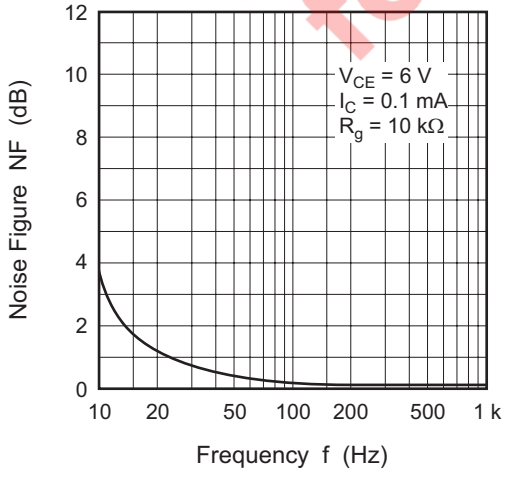
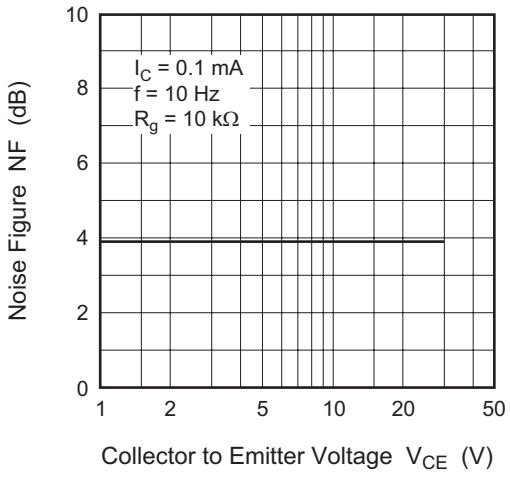


Noise Figure vs. Frequency



Noise Figure vs. Collector to Emitter Voltage



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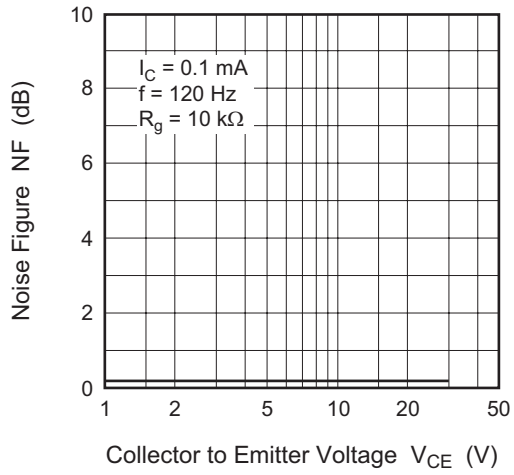

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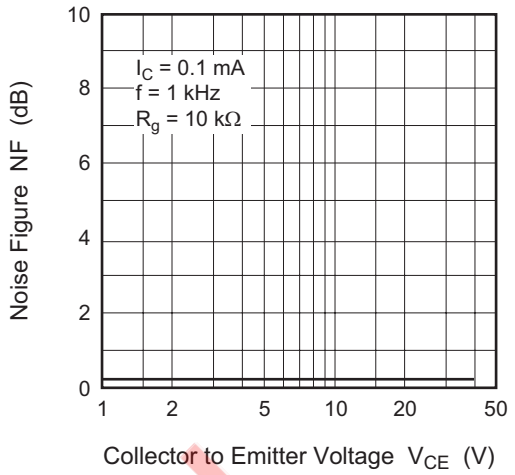
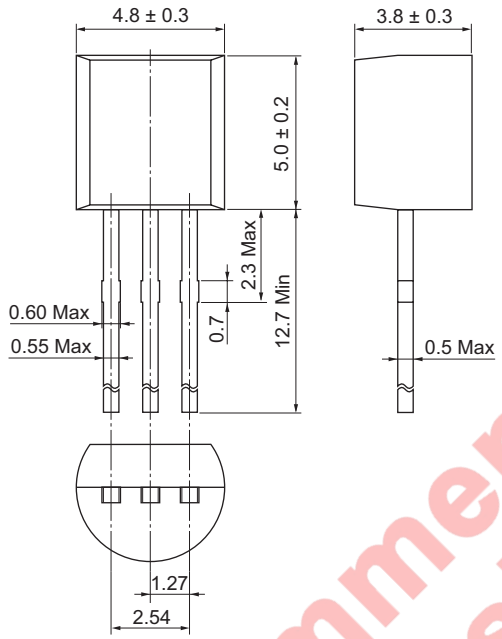


Package Dimensions

JEITA Package Code	RENESAS Code	Package Name	MASS[Typ.]
SC-43A	PRSS0003DA-A	TO-92(1) / TO-92(1)V	0.25g

Unit: mm



Ordering Information

Part Name	Quantity	Shipping Container
2SC1345ETZ-E 2SC1345FTZ-E	2500	Hold Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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